Characterization of Local Material Properties by Nano-probes

Takahashi LAB. [Nano-probing Technologies]

Centre for Interdisciplinary Research on Micro-Nano Methods

Nano-electronics

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Development of novel nano-probing technologies and nano-scale characterization of nano-materials for future device application



http://www.spm.iis.u-tokyo.ac.jp

c) Electrostatic Force at High Frequency

Ee-305

We aim at investigating electronic and optical properties in various nano-materials by means of nano-probe methods such as scanning tunneling microscopy (STM), atomic force microscopy (AFM), and related ones.

- **Development of Novel SPM Methods** Characterization of Solar Cell Materials • Photovoltaic properties • Fast imaging in AFM and minority carrier dynamics • Novel operation methods investigated by photo-assisted KFM for high performance SPMs (a) Topography (c) Photovoltage Decay Property (a) Topography (b) Photovoltage 200 Sample A [Ga/(Ga+In) = 23 9 tom A = 15.2 µse 0.5 µm Images of topography and electrostatic force on CIGS Frequency [Hz] observed by dual-bias modulation mode EFM 235 1.9 2.2 [mV] [µm] 434
 - Surface topography and photovoltage distribution on CIGS solar cell

and photovoltage decay property investigated by P-KFM

 Non-radiative recombination property of photo-carriers investigated by

photothermal mode AFM





Channel properties in CNT-FET examined by current-induced magnetic force measurements by MFM



Multi-functional SPM equipments:

Tunable Ti:Al₂O₃ laser

Variable temperature SPM







